# RT1N144X SERIES

**(Transistor)** 

UNIT: mm

Transistor With Resistor For Switching Application Silicon NPN Epitaxial Type

#### **DESCRIPTION**

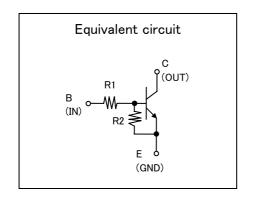
RT1N144X is a one chip transistor with built-in bias resistor, PNP type is RT1P144X.

#### **FEATURE**

•Built-in bias resistor (R1=10k  $\Omega$  ,R2=47k  $\Omega$  ).

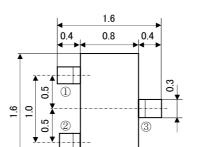
### **APPLICATION**

Inverted circuit, switching circuit, interface circuit, driver circuit.

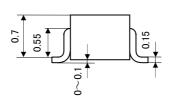


### OUTLINE DRAWING

# RT1N144C



RT1N144U



JEITA: — JEDEC: —

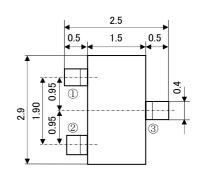
#### Terminal Connector

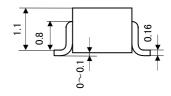
①:Base

2: Emitter

3: Collector

RT1N144M





JEITA: SC-59

JEDEC: Similar to TO-236

#### Terminal Connector

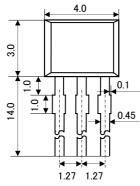
①:Base

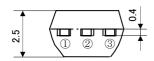
2: Emitter

3: Collector

#### RT1N144T



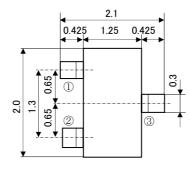


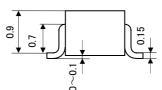


JEITA: — JEDEC: —

Terminal Connector

- 1: Emitter
- 2: Collector
- ③:Base

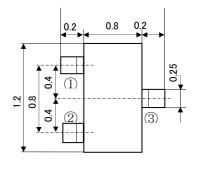


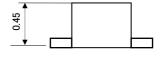


JEITA:SC-70 JEDEC:—

Terminal Connector

- (1):Base
- 2: Emitter
- 3: Collector





JEITA: —, JEDEC: — ISAHAYA: T-USM

Terminal Connector

- (1):Base
- 2:Emitter
- 3: Collector

# RT1N144X SERIES

**(Transistor)** 

Transistor With Resistor For Switching Application Silicon NPN Epitaxial Type

# MAXIMUM RATING (Ta=25°C)

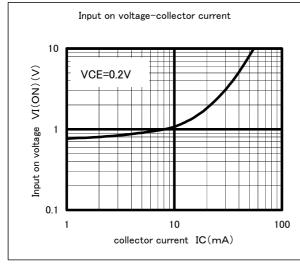
SYMBOL	PARAMETER	RATING					UNIT
		RT1N144T	RT1N144U	RT1N144M	RT1N144C	RT1N144S	UNIT
$V_{\text{CBO}}$	Collector to Base voltage	50					V
$V_{\sf EBO}$	Emitter to Base voltage	6					V
$V_{CEO}$	Collector to Emitter voltage	50					V
Ic	Collector current	100					
I <sub>CM</sub>	Peak Collector current	200					mA
Pc	Collector dissipation(Ta=25°C)	125(※)	150	200		450	mW
Tj	Junction temperature	+125 +150					°C
Tstg	Storage temperature	-55 <b>∼</b> +125					°C

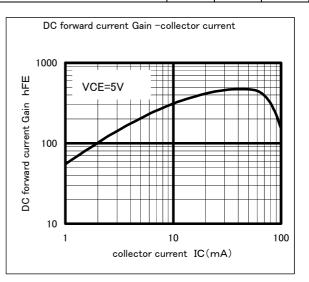
# ELECTRICAL CHARACTERISTICS (Ta=25°C)

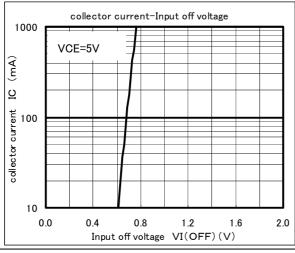
(※ ) package mounted on 9mm×19mm×1mm glass-epoxy substrate.

SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
		TEST CONDITION	MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	C to E break down voltage	I <sub>C</sub> =100 μ A, R <sub>BE</sub> =∞	50			٧
I <sub>CBO</sub>	Collector cut off current	$V_{CB}$ =50V, $I_{E}$ =0			0.1	μΑ
h <sub>FE</sub>	DC forward current gain	$V_{CE}$ =5V, I $_{C}$ =5mA	50			_
$V_{CE(sat)}$	C to E saturation voltage	$I_{C} = 10$ mA, $I_{B} = 0.5$ mA		0.1	0.3	V
$V_{I(ON)}$	Input on voltage	$V_{CE}$ =0.2V, I $_{C}$ =5mA		1.0	1.8	V
$V_{I(OFF)}$	Input off voltage	$V_{CE}$ =5V, I $_{C}$ =100 $\mu$ A	0.4	0.7		>
R <sub>1</sub>	Input resistance		7.0	10	13	kΩ
R <sub>2</sub> /R <sub>1</sub>	Resistance ratio		4.2	4.7	5.1	
f <sub>⊤</sub>	Gain band width product	$V_{CE}=6V$ , $I_{E}=-10mA$		200		MHz

TYPICAL CHARACTERISTICS









Marketing division, Marketing planning department 6-41 Tsukuba, Isahaya, Nagasaki, 854-0065 Japan

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